

TECHNICAL DATA
DATA SHEET 5332, REV. -**HERMETIC POWER SCHOTTKY RECTIFIER**
150°C Maximum Operation Temperature

DESCRIPTION: A 60-VOLT, 35 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC TO-254 PACKAGE.

MAXIMUM RATINGSALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	60	Volts
MAXIMUM DC OUTPUT CURRENT (@ $T_C=100^\circ\text{C}$) (Single, Doubler)	I_O	35	Amps
MAXIMUM DC OUTPUT CURRENT (@ $T_C=100^\circ\text{C}$) (Common Cathode, Common Anode)	I_O	35	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine)	I_{FSM}	400	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	1520	pF
MAXIMUM THERMAL RESISTANCE (Single)	$R_{\theta JC}$	1.25	$^\circ\text{C/W}$
MAXIMUM THERMAL RESISTANCE (Common Cathode, Common Anode, Doubler)	$R_{\theta JC}$	0.63	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	Top/Tstg	-55 to + 150	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	Top/Tstg	-55 to + 150	$^\circ\text{C}$

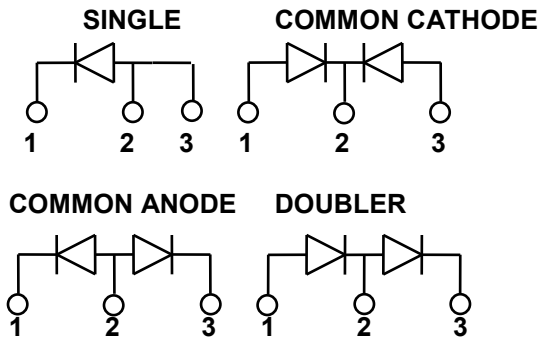
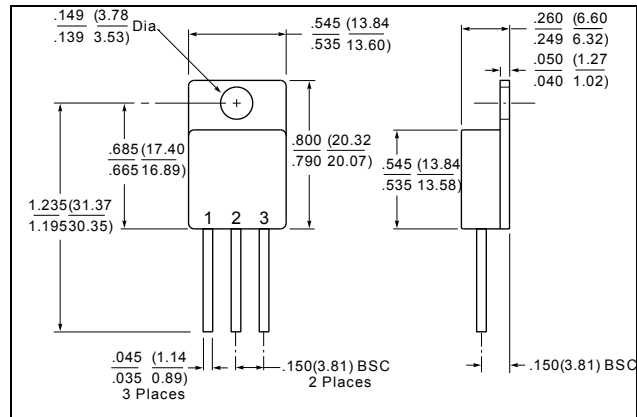
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 35\text{ Amps}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.86 0.93	Volts
MAXIMUM REVERSE CURRENT (I_r @ 60 V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.22 180	mA

SENSITRON

DATA SHEET 5332, REV. -

Mechanical Dimensions: In inches / mm



TO-254

PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	CATHODE/ ANODE	CATHODE

Curves shown are for bare die only.

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